

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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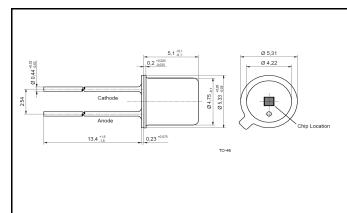


Product No: MTPD3650D-1.4



Optoelectronics

Radiation	Туре	Case
Ultraviolet	GaP Schottky	TO-46, UV glass + UG11 filter



#### Description:

Wide bandwidth and high spectral sensitivity in the UV range (245 nm - 400 nm), mounted in hermetically sealed TO-46 package with UG11 UV filter-glass window

#### **Applications**

Medical engineering (dermatology), output check of UV - lamps and gas burner flame, measurement and control of ecological parameters, radiation control for solarium, UV water purification facilities

## Absolute Maximum Ratings (Ta = 25°C)

ITEMS	SYMBOL	RATINGS	UNIT	
Active Area	Α	1.2	$mm^2$	
Temperature Coefficient of Ip	TC(Ip)	7	%K	
Operating Temperature Range	T <sub>amb</sub>	-40  to  +70	°C	
Storage Temperature Range	$T_{stg}$	-40 to +100	°C	
<b>A</b> cceptance Angle at 50% of $S_{\lambda}$	φ	50	deg.	

### Electrical & Optical Characteristics (Ta = 25°C)

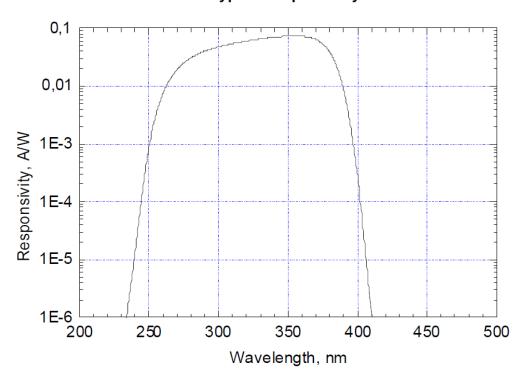
ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Breakdown Voltage 1*	Vr	Ir=10µA	5			V
Dark Current	ld	Vr=5V		5	30	рА
Peak Sensitivity Wavelength	$\lambda_p$	Vr=0V		365		nm
Responsitivity at $\lambda p$	$S_\lambda$	Vr=0V		0.07		A/W
Sensitivity Range at 1% of $S_{\!\lambda}$	λmin, λmax	Vr=0V	245		400	nm
Spectral Bandwidth at 50% of $S\lambda$	Δλ0.5	Vr=0V		85		nm
Shunt Resistance	Rsh	Vr=10mV	150	200		GΩ
Noise Equivalent Power	NEP	λ=365 nm		$1.8 \times 10^{-14}$		$W/\sqrt{Hz}$
Specific Detectivity	D*	λ=365 nm		5.9 x 10 <sup>12</sup>		cm . $\sqrt{\text{Hz}}$ . W <sup>-1</sup>
Junction Capacitance	Cj	Vr=0V		250		рF
Switching Time ( $R_L = 50\Omega$ )	t <sub>r</sub> , t <sub>f</sub>	Vr=5V		1; 20		ns
Photocurrent at $\lambda$ =365 nm	Iph	Vr=0V E <sub>e</sub> =1 mW/cm <sup>2</sup>		0.3		μΑ

1\* for information only

2014-04-07



### Typical responsivity





We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.

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